

Datasheet

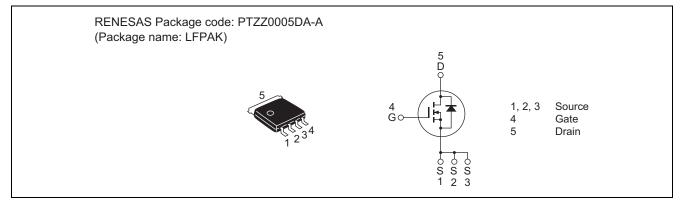
100V, 23A, 17m $\Omega$  max. Silicon N Channel Power MOS FET Power Switching

R07DS1058EJ0200 (Previous: REJ03G1887-0100) Rev.2.00 Apr 11, 2013

## Features

- High speed switching
- Low drive current
- Low on-resistance
  - $R_{DS(on)} = 13 \text{ m}\Omega \text{ typ.}$  (at  $V_{GS} = 10 \text{ V}$ )
- Pb-free
- Halogen-free
- High density mounting

## Outline



## **Absolute Maximum Ratings**

			$(Ta = 25^{\circ}C)$
ltem	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	100	V
Gate to source voltage	V <sub>GSS</sub>	±20	V
Drain current	ID	23	A
Drain peak current	Note1 I <sub>D(pulse)</sub>	92	A
Body-drain diode reverse drain current	I <sub>DR</sub>	23	A
Avalanche current	I <sub>AP</sub> Note 2	23	A
Avalanche energy	E <sub>AS</sub> Note 2	5.3	mJ
Channel dissipation	Pch Note3	60	W
Channel to Case Thermal Resistance	θch-C	2.08	°C/W
Channel temperature	Tch	150	٥C
Storage temperature	Tstg	-55 to +150	٥C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. Value at L=10uH, Tch =  $25^{\circ}$ C, Rg  $\geq 50 \Omega$ 

3. Tc = 25°C



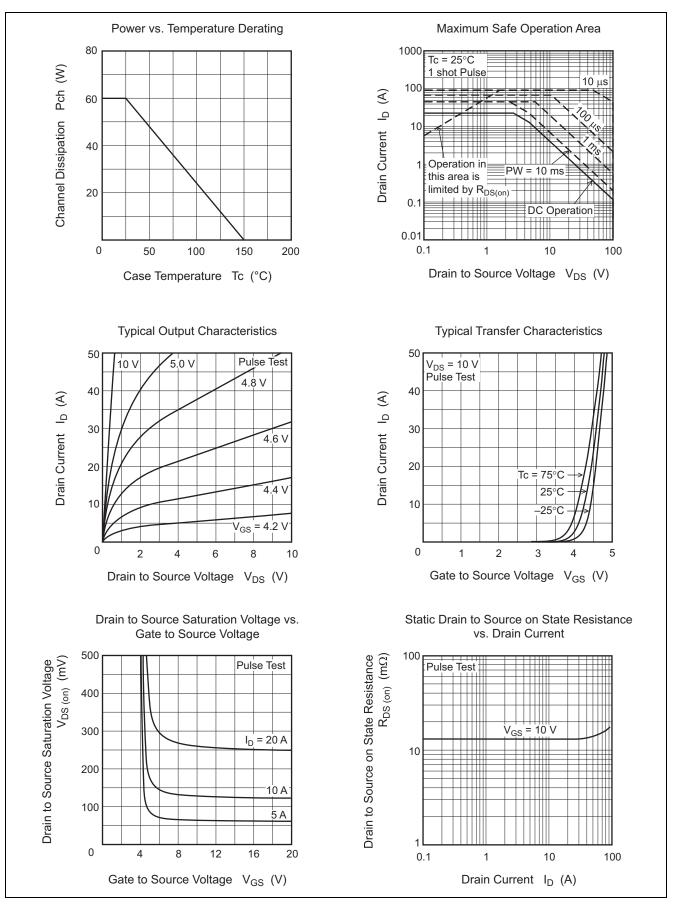
# **Electrical Characteristics**

						$(Ta = 25^{\circ}C)$
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	100	—		V	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$
Gate to source leak current	I <sub>GSS</sub>	_	—	±0.1	μA	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$
Zero gate voltage drain current	I <sub>DSS</sub>	_	—	1	μA	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$
Gate to source cutoff voltage	V <sub>GS(off)</sub>	2.0	—	4.0	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state resistance	R <sub>DS(on)</sub>	_	13	17	mΩ	$I_D = 11.5 \text{ A}, V_{GS} = 10 \text{ V}^{Note4}$
Forward transfer admittance	y <sub>fs</sub>	_	37	_	S	$I_D = 11.5 \text{ A}, V_{DS} = 10 \text{ V}^{Note4}$
Input capacitance	Ciss	_	2550	_	pF	$V_{DS} = 10 V, V_{GS} = 0 V,$
Output capacitance	Coss	_	420	_	pF	f = 1 MHz
Reverse transfer capacitance	Crss	_	100	_	pF	
Gate Resistance	Rg	_	0.5	_	Ω	
Total gate charge	Qg	_	35	_	nC	$V_{DD} = 50 \text{ V}, \text{ V}_{GS} = 10 \text{ V},$
Gate to source charge	Qgs	_	11	_	nC	I <sub>D</sub> = 23 A
Gate to drain charge	Qgd	_	7.0	_	nC	
Turn-on delay time	t <sub>d(on)</sub>	_	14	_	ns	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 11.5 \text{ A},$
Rise time	tr	_	4.2	_	ns	$\label{eq:VDD} \begin{array}{l} V_{DD} \cong 30 \ V, \ R_{L} = 2.6 \ \Omega, \\ Rg = 4.7 \ \Omega \end{array}$
Turn-off delay time	t <sub>d(off)</sub>	_	34	_	ns	
Fall time	t <sub>f</sub>	_	6.2	_	ns	
Body-drain diode forward voltage	V <sub>DF</sub>		0.8	1.1	V	$I_F = 23 \text{ A}, V_{GS} = 0 \text{ V}^{Note4}$
Body-drain diode reverse recovery time	t <sub>rr</sub>	_	50		ns	I <sub>F</sub> = 23 A, V <sub>GS</sub> = 0 V
						di <sub>F</sub> / dt = 100 A/ μs

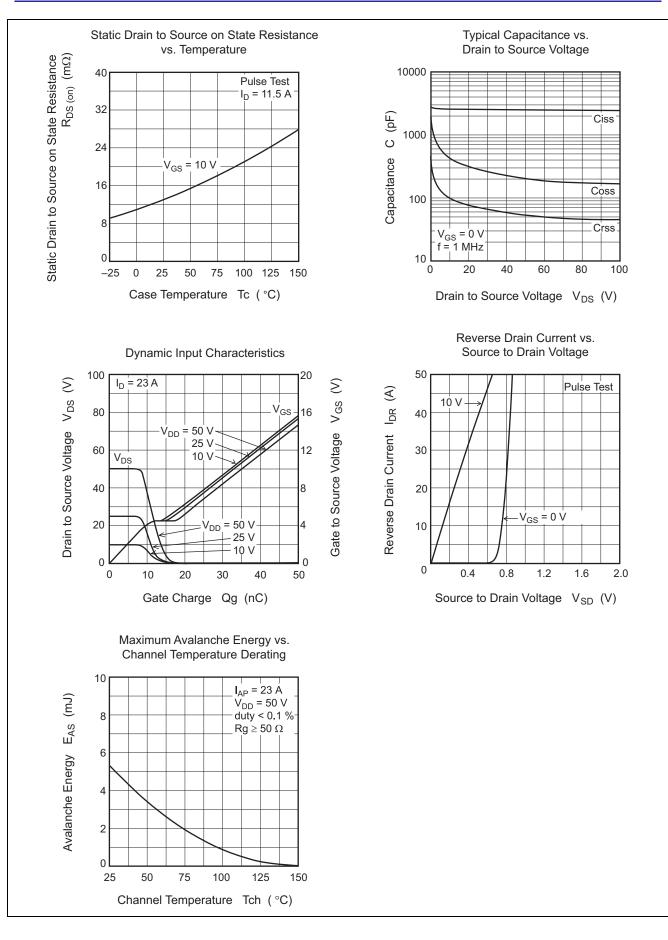
Notes: 4. Pulse test

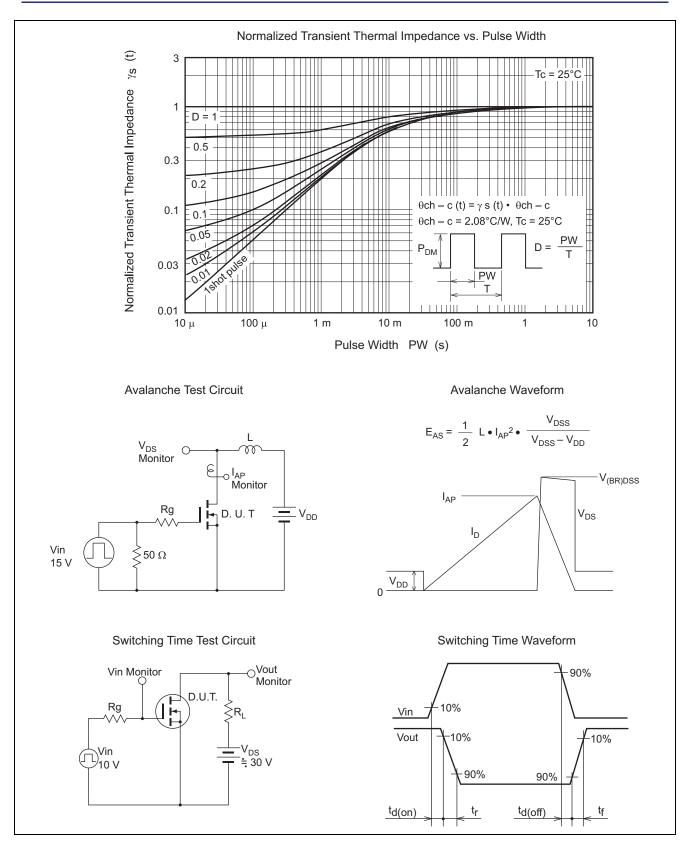


## **Main Characteristics**

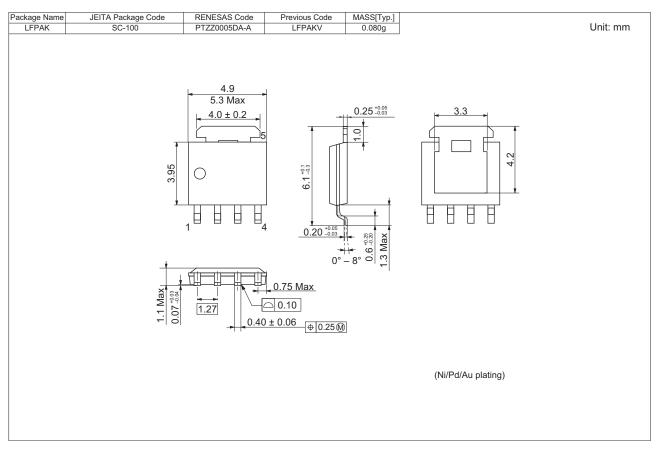








## **Package Dimensions**



## **Ordering Information**

Part No.	Quantity	Shipping Container
RJK1055DPB-00-J5	2500 pcs	Taping



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